

Test Report Page: 1 of 7 No.: CE/2016/82771 Date: 2016/08/19

SHINGTECH ELECTRONICS CO., LTD.

NO. 303, SEC. 2, NANSHAN RD., LUZHU DISTRICT, TAOYUAN CITY 338, TAIWAN (R. O. C.)

The following sample(s) was/were submitted and identified by/on behalf of the applicant as:

: SHINGTECH ELECTRONICS CO., LTD. Sample Submitted By

Sample Description : 無鉛噴錫

Style/Item No. : ROHS-無鉛噴錫 Sample Receiving Date : 2016/08/12

Testing Period : 2016/08/12 TO 2016/08/19

: As specified by client, with reference to RoHS 2011/65/EU Annex II and amending **Test Requested**

Directive (EU) 2015/863 to determine Cadmium, Lead, Mercury, Cr(VI), PBBs, PBDEs,

DBP, BBP, DEHP, DIBP contents in the submitted sample.

Test Method : Please refer to next page(s). Test Result(s) : Please refer to next page(s).





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Test Result(s)

PART NAME No.1 **GREEN PCB**

Test Item(s)	Unit	Method	MDL	Result
	Onit			No.1
Cadmium (Cd)	mg/kg	With reference to IEC 62321-5 (2013) and performed by ICP-AES.	2	n.d.
Lead (Pb)	mg/kg		2	n.d.
Mercury (Hg)	mg/kg	With reference to IEC 62321-4	2	n.d.
		(2013) and performed by ICP-AES.		
Hexavalent Chromium Cr(VI)	mg/kg	With reference to IEC 62321 (2008) and performed by UV-VIS.	2	n.d.
Sum of PBBs	mg/kg	With reference to IEC 62321-6 (2015) and performed by GC/MS.	-	n.d.
Monobromobiphenyl	mg/kg		5	n.d.
Dibromobiphenyl	mg/kg		5	n.d.
Tribromobiphenyl	mg/kg		5	n.d.
Tetrabromobiphenyl	mg/kg		5	n.d.
Pentabromobiphenyl	mg/kg		5	n.d.
Hexabromobiphenyl	mg/kg		5	n.d.
Heptabromobiphenyl	mg/kg		5	n.d.
Octabromobiphenyl	mg/kg		5	n.d.
Nonabromobiphenyl	mg/kg		5	n.d.
Decabromobiphenyl	mg/kg		5	n.d.
Sum of PBDEs	mg/kg		-	n.d.
Monobromodiphenyl ether	mg/kg		5	n.d.
Dibromodiphenyl ether	mg/kg		5	n.d.
Tribromodiphenyl ether	mg/kg		5	n.d.
Tetrabromodiphenyl ether	mg/kg		5	n.d.
Pentabromodiphenyl ether	mg/kg		5	n.d.
Hexabromodiphenyl ether	mg/kg		5	n.d.
Heptabromodiphenyl ether	mg/kg		5	n.d.
Octabromodiphenyl ether	mg/kg		5	n.d.
Nonabromodiphenyl ether	mg/kg		5	n.d.
Decabromodiphenyl ether	mg/kg		5	n.d.



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Test Item(s)	Unit	Method	MDL	Result
				No.1
DBP (Dibutyl phthalate) (CAS No.: 84-74-2)	mg/kg	With reference to IEC 62321-8/CD (2013). Analysis was performed by GC/MS.	50	n.d.
DIBP (Di-isobutyl phthalate) (CAS No.: 84-69-5)	mg/kg		50	n.d.
DEHP (Di- (2-ethylhexyl) phthalate) (CAS No.: 117-81-7)	mg/kg		50	n.d.
BBP (Butyl Benzyl phthalate) (CAS No.: 85-68-7)	mg/kg		50	n.d.

Note:

1. mg/kg = ppm; 0.1wt% = 1000ppm

2. n.d. = Not Detected

3. MDL = Method Detection Limit

4. " - " = Not Regulated



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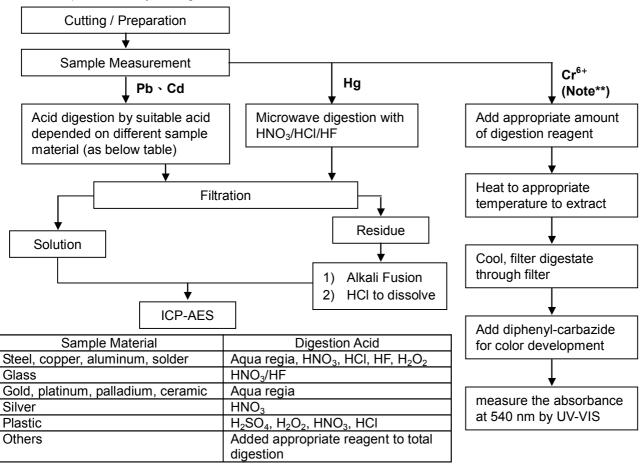
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Analytical flow chart of Heavy Metal (IEC 62321)

These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr⁶⁺ test method excluded)

Technician: JR Wang

Supervisor: Troy Chang



Note** (For IEC 62321)

- (1) For non-metallic material, add alkaline digestion reagent and heat to 90~95℃.
- (2) For metallic material, add pure water and heat to boiling.



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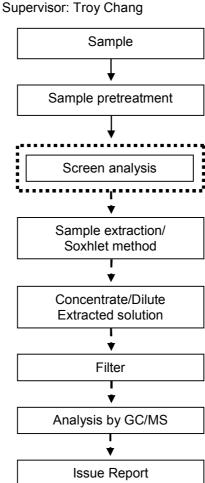
Analytical flow chart - PBB/PBDE

Technician: Yaling Tu

First testing process -

Optional screen process

Confirmation process





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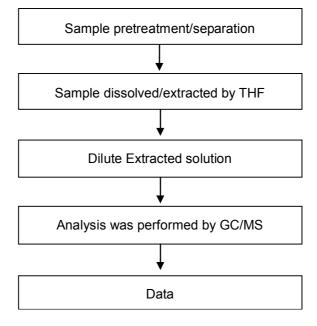
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Analytical flow chart - Phthalate

Technician: Andy Shu Supervisor: Troy Chang

[Test method: IEC 62321-8]





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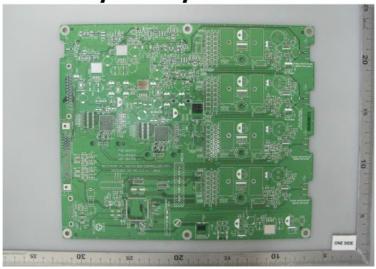
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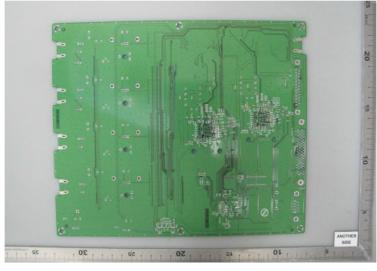
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* The tested sample / part is marked by an arrow if it's shown on the photo. *

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** End of Report **